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Fairchild Semiconductor FJX3009RTF

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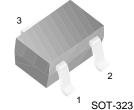




FJX3009R

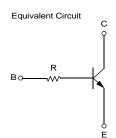
Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R=4.7KΩ)
- Complement to FJX4009R









NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units | |
|------------------|-----------------------------|-----------|-------|--|
| V _{CBO} | Collector-Base Voltage | 40 | V | |
| V _{CEO} | Collector-Emitter Voltage | 40 | V | |
| V_{EBO} | Emitter-Base Voltage | 5 | V | |
| С | Collector Current | 100 | mA | |
| Pc | Collector Power Dissipation | 200 | mW | |
| Т | Junction Temperature | 150 | °C | |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C | |

Electrical Characteristics T_a=25°C unless otherwise noted

| | ŭ | | | | | |
|-----------------------|--------------------------------------|---|------|------|------|-------|
| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C =100μA, I _E =0 | 40 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _E =1mA, I _B =0 | 40 | | | V |
| I _{CBO} | Collector Cut-off Current | V_{CB} =30V, I_E =0 | | | 0.1 | μΑ |
| h _{FE} | DC Current Gain | V _{CE} =5V, I _C =1mA | 100 | | 600 | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =10mA, I _B =1mA | | | 0.3 | V |
| C _{ob} | Output Capacitance | V _{CB} =10V, I _E =0 f=1MHz | | 3.70 | | pF |
| f _T | Current Gain Bandwidth Product | V _{CE} =10V, I _C =5mA | | 250 | | MHz |
| R | Input Resistor | | 3.2 | 4.7 | 6.2 | ΚΩ |

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Typical Characteristics

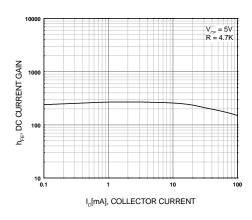


Figure 1. DC current Gain

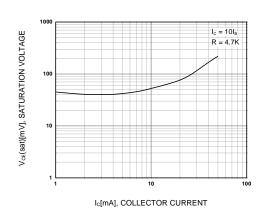


Figure 2. Collector-Emitter Saturation Voltage

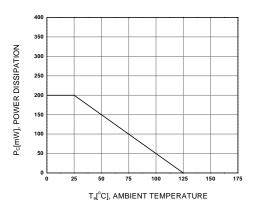


Figure 3. Power Derating

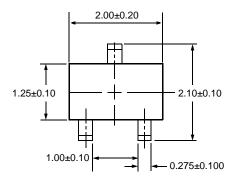
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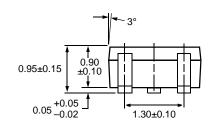
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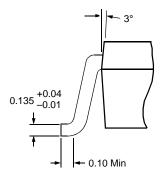


Package Dimensions

SOT-323







Dimensions in Millimeters

Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of FJX3009RTF - TRANS PREBIAS NPN 200MW SOT323

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| EnSigna™ | I ² C™ | OCX^{TM} | RapidConfigure™ | UHC™ |
| Across the board. | Around the world.™ | OCXPro™ | RapidConnect™ | UltraFET [®] |
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|--------------------------|---------------------------|---|
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